3A High Performance Step-Up DC-DC Converter

General Description

The RTQ9297-QT includes a high performance step-up DC-DC converter that provides a regulated supply voltage for active-matrix thin-film transistor (TFT) liquid-crystal displays (LCDs).

The Boost Converter incorporates current mode, fixedfrequency, pulse-width modulation (PWM) circuitry with a built-in N-Channel power MOSFET to achieve high efficiency and fast transient response.

The RTQ9297-QT is available in a WDFN -10SL 3x3 package.

Ordering Information

Note :

Richtek products are :

- RoHS compliant and compatible with the current require ments of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

QM=YM DNN QM= : Product Code YMDNN : Date Code

Features

- **High Efficiency Up to 90%**
- Adjustable Output Voltage : V_{DD} to 24V
- **Wide Input Supply Voltage : 2.6V to 5.5V**
- **Input Under Voltage Lockout**
- **Pin-Programmable Switching Frequency 640kHz/ 1.2MHz**
- **Programmable Soft-Start**
- **AEC-Q100 Grade 2 Qualified**
- **Small 10S-Lead WDFN Package**
- **RoHS Compliant and Halogen Free**

Applications

- Notebook Computer Displays
- LCD Monitor Panels
- LCD TV Panels

Pin Configuration

WDFN-10SL 3x3

Simplified Application Circuit

Functional Block Diagram

Operation

The RTQ9297-QT includes a high performance step-up DC-DC converter that provides a regulated supply voltage for active-matrix thin-film transistor (TFT) liquid-crystal displays (LCDs).

The Boost Converter covering a wide VIN range from 2.6V to 5.5V. It performs high efficiency and fast transient responses to generate source driver supplies for TFT LCD display. The converter uses a current mode, pulse width modulation (PWM) topology with a built in N-MOSFET to achieve high efficiency and fast transient response in TFT-LCD applications. The output voltage can be adjusted by setting the resistive voltage-divider sensing at the FB pin. The error amplifier varies the COMP voltage by sensing the FB pin to regulate the output voltage.

Functional Pin Description

Absolute Maximum Ratings (Note 1)

Recommended Operating Conditions (Note 4)

Electrical Characteristics

(V_{DD} = 3.3V, T_A = -40°C to 105°C, unless otherwise specified)

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

- **Note 3.** Devices are ESD sensitive. Handling precaution is recommended.
- **Note 4.** The device is not guaranteed to function outside its operating conditions.

Note 2. θ_{JA} is measured at T_A = 25°C on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JC} is measured at the exposed pad of the package.

Typical Application Circuit

Typical Operating Characteristics

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Application Information

The RTQ9297-QT contains a high performance boost regulator to generate voltage for the panel source driver ICs. The following content contains the detailed description and the information of component selection.

Boost Regulator

The boost regulator is a high efficiency current-mode PWM architecture with 640K / 1.2MHz operation frequency. It performs fast transient responses to generate source driver supplies for TFT LCD display. The high operation frequency allows smaller components used to minimize the thickness of the LCD panel. The output voltage setting can be achieved by setting the resistive voltage-divider sensing at FB pin. The error amplifier varies the COMP voltage by sensing the FB pin to regulate the output voltage. For better stability, the slope compensation signal summed with the current-sense signal will be compared with the COMP voltage to determine the current trip point and duty cycle.

Soft-Start

The RTQ9297-QT provides soft-start function to minimize the inrush current. When power on, an internal constant current charges an external capacitor. The rising voltage rate on the COMP pin is limited during the charging period and the inductor peak current will also be limited at the same time. When power off, the external capacitor will be discharged for next soft start time.

The soft-start function is implemented by the external capacitor with a 4μA constant current charging to the softstart capacitor. Therefore, the capacitor should be large enough for output voltage regulation. Typical value for softstart capacitor range is 33nF. The available soft-start capacitor range is from 10nF to 100nF.

Output Voltage Setting

The regulated output voltage is shown as following equation :

 A _{AVDD} = 1.24V x $\left(1 + \frac{R_1}{R_2}\right)$ V_{AVDD} = 1.24V x $\left(1+\frac{R_1}{R_2}\right)$

The recommended value for R2 should be up to 10kΩ without some sacrificing. To place the resistor divider as close as possible to the chip can reduce noise sensitivity.

Loop Compensation

The voltage feedback loop can be compensated with an external compensation network consisted of R_{COMP} and C_{COMP}. Choose R_{COMP} to set high frequency integrator gain for fast transient response and C_{COMP} to set the integrator zero to maintain loop stability. For typical application $V_{DD} = 3.3V$, $V_{AVDD} = 13.6V$, $C4 = 4.7\mu F \times 3$, L = 3.6uH, the recommended value for compensation is as below : $R_{COMP} = 56k\Omega$, $C_{COMP} = 330pF$.

Over Current Protection

The RTQ9297-QT boost converter has over-current protection to limit peak inductor current. It prevents large current from damaging the inductor and diode. During the ON-time, once the inductor current exceeds the current limit, the internal LX switch turns off immediately and shortens the duty cycle. Therefore, the output voltage drops if the over-current condition occurs. The current limit there should is also affected by the input voltage, duty cycle and inductor value.

Over Temperature Protection

The RTQ9297-QT boost converter has thermal protection function to prevent the chip from overheating. When the junction temperature exceeds 155°C, it will shut down the device. Once the device cools down by approximately 30°C, it will start to operate normally. For continuous operation, do not operate over the maximum junction temperature rating 125°C.

Inductor Selection

The inductance depends on the maximum input current. The inductor current ripple is 20% to 40% of maximum input current that is a general rule. Assume, choose 40% as the criterion then

$$
I_{VDD(MAX)} = \frac{V_{AVDD} \times I_{AVDD(MAX)}}{\eta \times V_{DD}}
$$

 I_{RIPPLE} = 0.4 x $I_{VDD(MAX)}$

Where η is the efficiency, $I_{IN(MAX)}$ is the maximum input current, I_{RIPPLE} is the inductor current ripple. Beside, the input peak current is maximum input current plus half of inductor current ripple.

I_{PEAK} = 1.2 x $I_{VDD(MAX)}$

Note that the saturated current of inductor must be greater than I_{PEAK} . The inductance can be eventually determined as follow equation :

$$
L = \frac{\eta \times (V_{DD})^2 \times (V_{AVDD} - V_{DD})}{0.4 \times (V_{AVDD})^2 \times I_{AVDD(MAX)} \times f_{OSC}}
$$

Where $f_{\rm OSC}$ is the switching frequency. To consider the system performance, a shielded inductor is preferred to avoid EMI issue.

Diode Selection

Schottky diode is a good choice for an asynchronous Boost converter due to the small forward voltage. However, power dissipation, reverse voltage rating and pulsating peak current are the important parameters for Schottky diode selection. It is recommended to choose a suitable diode whose reverse voltage rating is greater than the maximum output voltage.

Capacitor Selection

Output ripple voltage is an important index for estimating the performance. This portion consists of two parts, one is the product of input current and ESR of output capacitor, another part is formed by charging and discharging process of output capacitor. Refer to Figure 1, evaluate DV_{out} by ideal energy equalization. According to the definition of Q, the Q value can be calculated as following equation :

$$
Q = \frac{1}{2} \times \left[\left(I_{IN} + \frac{1}{2} \Delta I_L - I_{OUT} \right) + \left(I_{IN} - \frac{1}{2} \Delta I_L - I_{OUT} \right) \right]
$$

$$
\times \frac{V_{IN}}{V_{OUT}} \times \frac{1}{f_{SW}} = C_{OUT} \times \Delta V_{OUT1}
$$

where f_{SW} is the switching frequency, and ΔI_L is the inductor ripple current. Move C_{OUT} to the left side to estimate the value of ΔV_{OUT1} as the following equation :

$$
\Delta V_{\text{OUT1}} = \frac{\text{D} \times \text{I} \times \text{I}}{\eta \times \text{C} \times \text{I} \times \text{f} \times \text{I}}
$$

Finally, by taking ESR into consideration, the overall output ripple voltage can be determined as the following equation :

$$
\Delta V_{OUT} = I_{IN} \times ESR + \frac{D \times I_{OUT}}{\eta \times C_{OUT} \times f_{SW}}
$$

Figure 1. The Output Ripple Voltage without the Contribution of ESR

Input Capacitor Selection

Low ESR ceramic capacitors are recommended for input capacitor applications. Low ESR will effectively reduce the input voltage ripple caused by switching operation. A 10μF is sufficient for most applications. Nevertheless, this value can be decreased for lower output current requirement. Another consideration is the voltage rating of the input capacitor must be greater than the maximum input voltage.

Thermal Considerations

The junction temperature should never exceed the absolute maximum junction temperature $T_{J(MAX)}$, listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula :

$$
P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}
$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating

Conditions is 125°C. The junction-to-ambient thermal resistance, θ_{JA} , is highly package dependent. For a WDFN-10SL 3x3, the thermal resistance, θ_{JA} , is 30.5°C/ W on a standard JEDEC 51-7 high effective-thermalconductivity four-layer test board. The maximum power dissipation at $T_A = 25^{\circ}$ C can be calculated as below :

P_{D(MAX)} = (125°C – 25°C) / (30.5°C/W) = 3.27W for a WDFN-10SL 3x3 package.

The maximum power dissipation depends on the operating ambient temperature for the fixed $T_{J(MAX)}$ and the thermal resistance, $θ_{JA}$. The derating curves in Figure 2 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

Figure 2. Derating Curve of Maximum Power Dissipation

Layout Considerations

For high frequency switching power supplies, the PCB layout is important to get good regulation, high efficiency and stability. The following descriptions are the guidelines for better PCB layout.

- For good regulation, place the power components as close as possible. The traces should be wide and short enough especially for the high-current output loop.
- ▶ The feedback voltage-divider resistors must be near the feedback pin. The divider center trace must be shorter and the trace must be kept away from any switching nodes.
- The compensation circuit should be kept away from the power loops and be shielded with a ground trace to prevent any noise coupling.
- Minimize the size of the LX node and keep it wide and shorter. Keep the LX node away from the FB.
- The exposed pad of the chip should be connected to a strong ground plane for maximum thermal consideration.

Figure 3. PCB Layout Guide

Outline Dimension

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

W-Type 10SL DFN 3x3 Package

Footprint Information

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